



# 2SB1143/2SD1683

## 50V/4A Switching Applications

An ON Semiconductor Company

### Applications

- Voltage regulators, relay drivers, lamp drivers, electrical equipment.

### Features

- Adoption of FBET, MBIT processes.
- Low saturation voltage.
- Large current capacity and wide ASO.

( ) : 2SB1143

### Specifications

**Absolute Maximum Ratings** at  $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CB0}$		(-)60	V
Collector-to-Emitter Voltage	$V_{CEO}$		(-)50	V
Emitter-to-Base Voltage	$V_{EBO}$		(-)6	V
Collector Current	$I_C$		(-)4	A
Collector Current (Pulse)	$I_{CP}$		(-)6	A
Collector Dissipation	$P_C$		1.5	W
		$T_c=25^\circ\text{C}$	10	W
Junction Temperature	$T_J$		150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ\text{C}$

**Electrical Characteristics** at  $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = (-)40\text{V}, I_E = 0$			(-)1	$\mu\text{A}$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = (-)4\text{V}, I_C = 0$			(-)1	$\mu\text{A}$
DC Current Gain	$h_{FE1}$	$V_{CE} = (-)2\text{V}, I_C = (-)100\text{mA}$	100*		560*	
	$h_{FE2}$	$V_{CE} = (-)2\text{V}, I_C = (-)3\text{A}$	40			
Gain-Bandwidth Product	$f_T$	$V_{CE} = (-)10\text{V}, I_C = (-)50\text{mA}$		150		MHz

\* ; The 2SB1143/2SD1683 are classified by 100mA  $h_{FE}$  as follows :

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Rank	R	S	T	U
$h_{FE}$	100 to 200	140 to 280	200 to 400	280 to 560

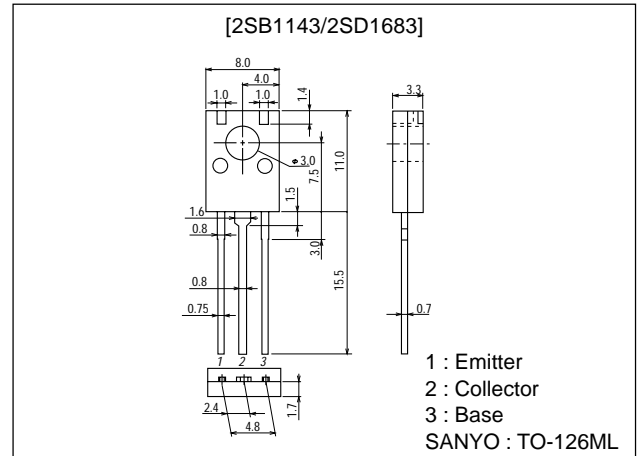
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### Package Dimensions

unit:mm

2042B

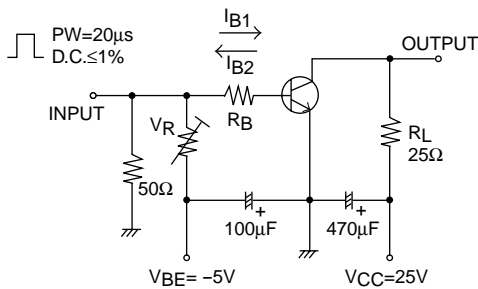


# 2SB1143/2SD1683

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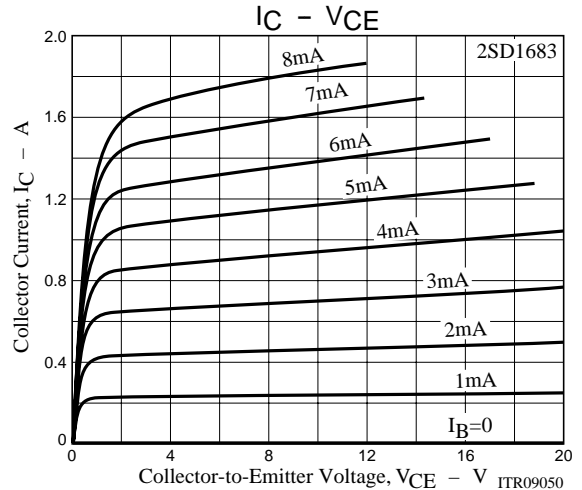
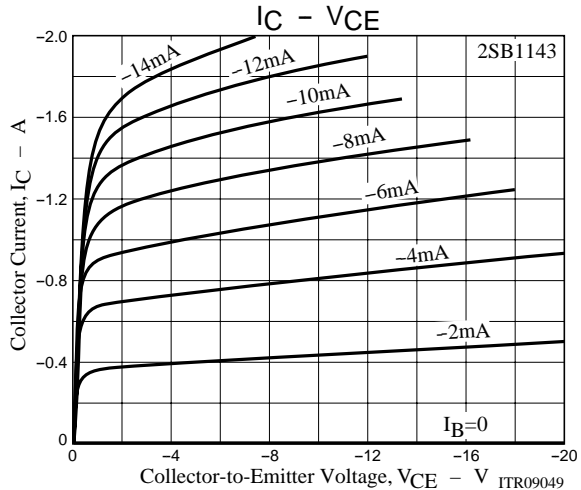
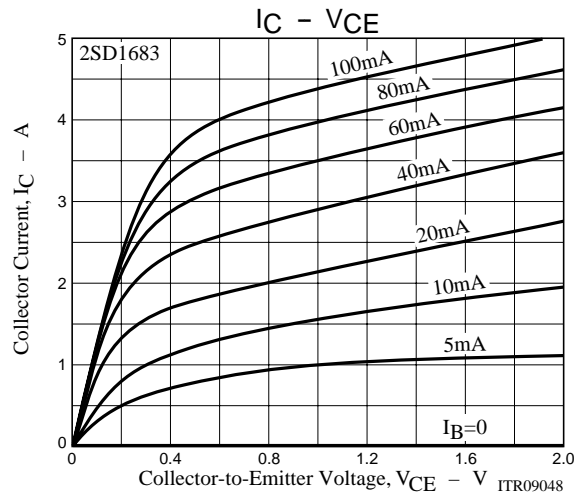
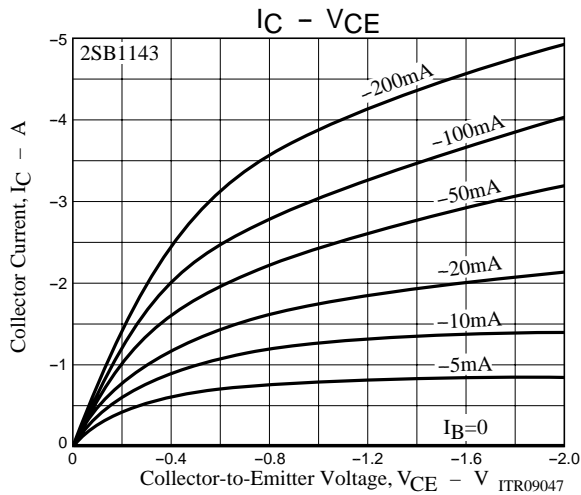
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output Capacitance	$C_{ob}$	$V_{CB}=(-)10V, f=1MHz$		(39)25		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)2A, I_B=(-)100mA$		(-350)	(-700)	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)2A, I_B=(-)100mA$		190	500	mV
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-60)			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-50)			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-6)			V
Turn-ON Time	$t_{on}$	See specified Test Circuit		(70)70		ns
Storage Time	$t_{stg}$	See specified Test Circuit		(450)		ns
Fall Time	$t_f$	See specified Test Circuit		650		ns
				(30)35		ns

## Switching Time Test Circuit

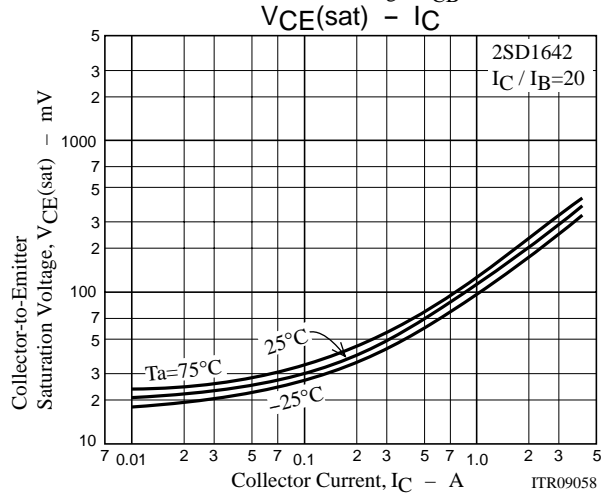
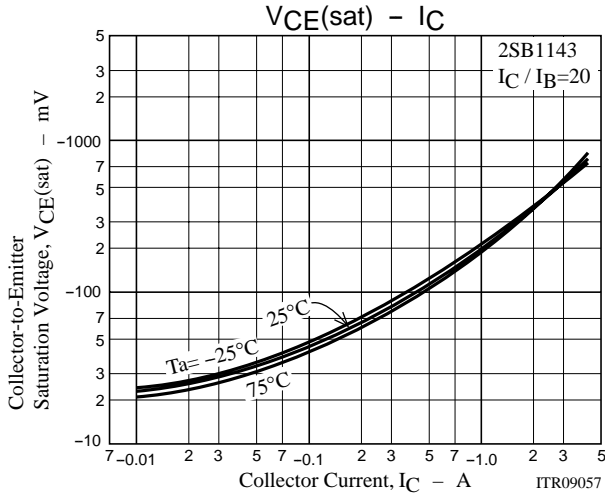
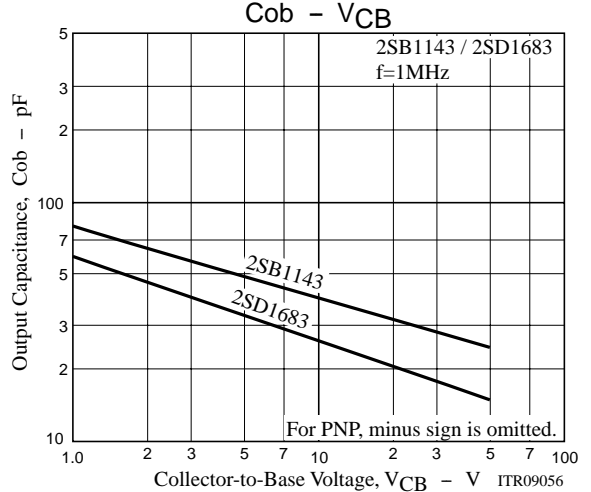
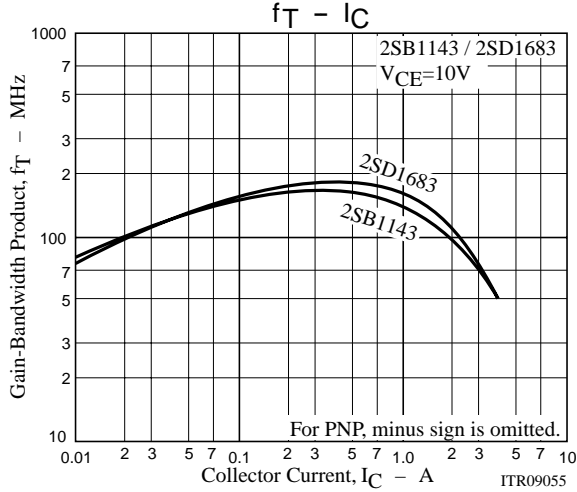
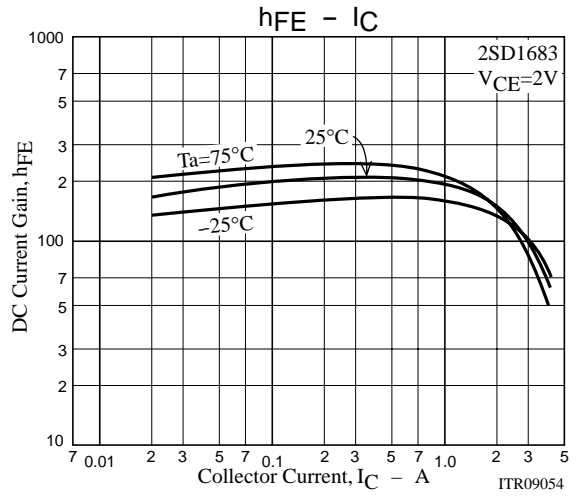
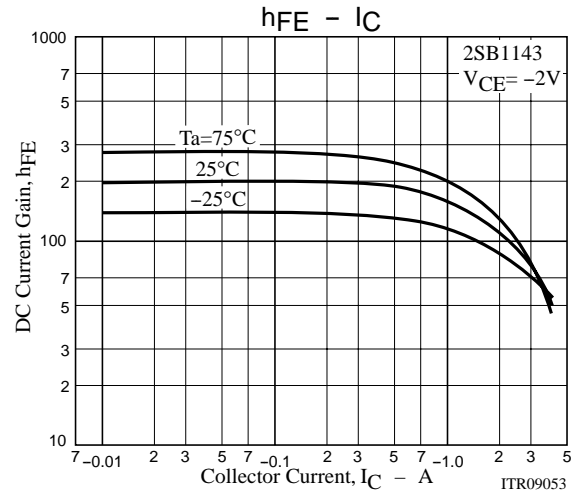
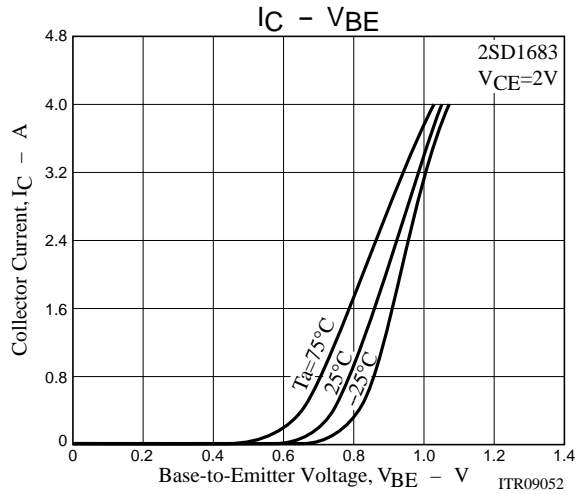
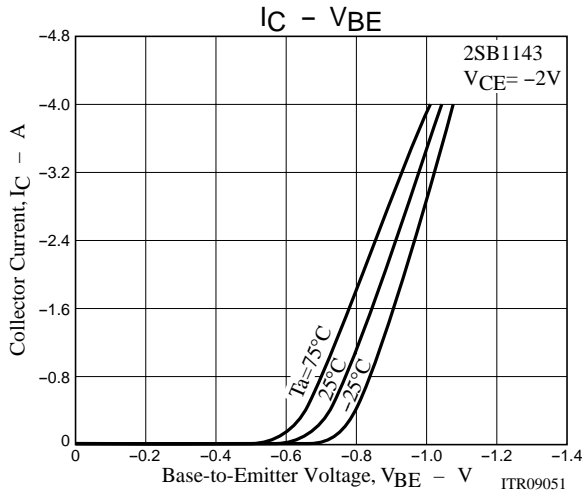


$$I_C = 10I_{B1} = -10I_{B2} = 1A$$

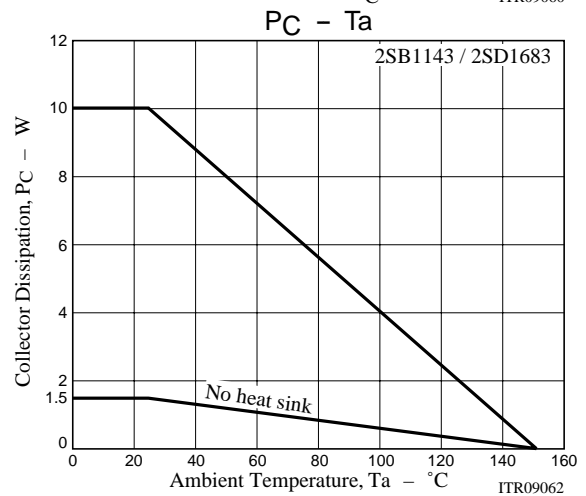
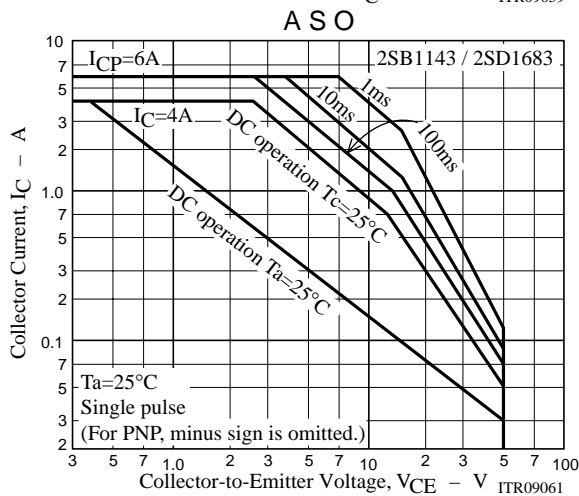
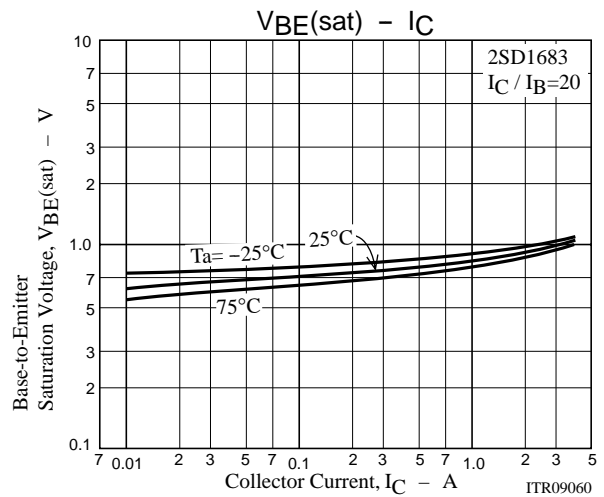
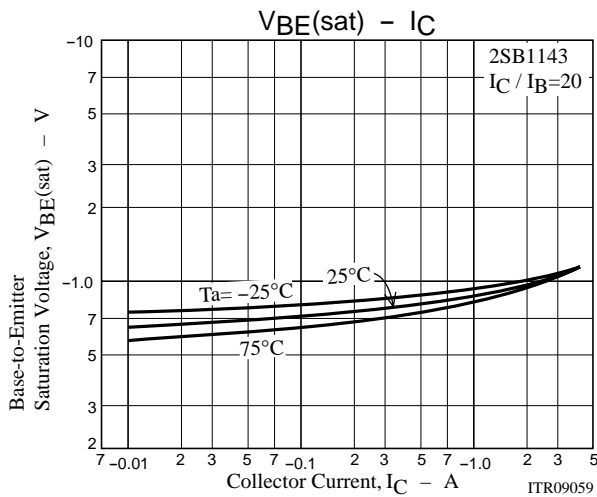
(For PNP, the polarity is reversed.)



# 2SB1143/2SD1683



## 2SB1143/2SD1683



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